## MJE15028, MJE15030 (NPN) MJE15029, MJE15031 (PNP)

Preferred Device
Complementary Silicon Plastic Power Transistors

These devices are designed for use as high-frequency drivers in audio amplifiers.

## Features

- DC Current Gain Specified to 4.0 Amperes

$$
\begin{aligned}
\mathrm{h}_{\mathrm{FE}} & =40(\mathrm{Min}) @ \mathrm{I}_{\mathrm{C}}=3.0 \mathrm{Adc} \\
& =20(\mathrm{Min}) @ \mathrm{I}_{\mathrm{C}}=4.0 \mathrm{Adc}
\end{aligned}
$$

- Collector-Emitter Sustaining Voltage -

$$
\begin{aligned}
\mathrm{V}_{\mathrm{CEO}(\mathrm{sus})} & =120 \mathrm{Vdc}(\mathrm{Min}) ; \text { MJE15028, MJE15029 } \\
& =150 \mathrm{Vdc}(\mathrm{Min}) ; \text { MJE15030, MJE15031 }
\end{aligned}
$$

- High Current Gain - Bandwidth Product

$$
\mathrm{f}_{\mathrm{T}}=30 \mathrm{MHz}(\mathrm{Min}) @ \mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}
$$

- TO-220AB Compact Package
- $\mathrm{Pb}-$ Free Packages are Available*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Collector-Emitter Voltage MJE15028, MJE15029 MJE15030, MJE15031 | $\mathrm{V}_{\text {CEO }}$ | $\begin{aligned} & 120 \\ & 150 \end{aligned}$ | Vdc |
| Collector-Base Voltage <br> MJE15028, MJE15029 <br> MJE15030, MJE15031 | $\mathrm{V}_{\mathrm{CB}}$ | $\begin{aligned} & 120 \\ & 150 \end{aligned}$ | Vdc |
| Emitter-Base Voltage | $\mathrm{V}_{\mathrm{EB}}$ | 5.0 | Vdc |
| Collector Current $\begin{aligned} & \text { - Continuous } \\ & \text { - Peak }\end{aligned}$ | $\begin{aligned} & \\ & \mathrm{IC}_{\mathrm{C}} \end{aligned}$ | $\begin{aligned} & 8.0 \\ & 16 \end{aligned}$ | Adc |
| Base Current | $\mathrm{I}_{\mathrm{B}}$ | 2.0 | Adc |
| Total Device Dissipation @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | $\begin{gathered} \hline 50 \\ 0.40 \end{gathered}$ | $\begin{gathered} \mathrm{W} \\ \mathrm{~W} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| Total Device Dissipation @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ Derate above $25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | $\begin{gathered} 2.0 \\ 0.016 \end{gathered}$ | $\begin{gathered} \mathrm{W} \\ \mathrm{~W} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| Operating and Storage Junction Temperature Range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | $\begin{gathered} -65 \text { to } \\ +150 \end{gathered}$ | ${ }^{\circ} \mathrm{C}$ |

THERMAL CHARACTERISTICS

| Characteristics | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Thermal Resistance, Junction-to-Case | $\mathrm{R}_{\text {өJC }}$ | 2.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\text {өJA }}$ | 62.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## ON Semiconductor ${ }^{\circledR}$

http://onsemi.com
8 AMPERE
POWER TRANSISTORS COMPLEMENTARY SILICON 120-150 VOLTS, 50 WATTS


TO-220AB CASE 221A-09 STYLE 1

## MARKING DIAGRAM


MJE150xx = Device Code

$$
x=28,29,30 \text {, or } 31
$$

$$
\mathrm{G} \quad=\text { Pb-Free Package }
$$

$$
\text { A } \quad=\text { Assembly Location }
$$

$$
Y \quad=\text { Year }
$$

WW = Work Week

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

## MJE15028, MJE15030 (NPN) MJE15029, MJE15031 (PNP)

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic |  | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |
| $\begin{aligned} & \text { Collector-Emitter Sustaining Voltage (Note 1) } \\ & \quad\left(I_{C}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right) \end{aligned}$ | MJE15028, MJE15029 MJE15030, MJE15031 | $\mathrm{V}_{\text {CEO(sus) }}$ | $\begin{aligned} & 120 \\ & 150 \end{aligned}$ | - | Vdc |
| Collector Cutoff Current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{CE}}=120 \mathrm{Vdc}, \mathrm{I}_{\mathrm{B}}=0\right) \\ & \left(\mathrm{V}_{\mathrm{CE}}=150 \mathrm{Vdc}, \mathrm{I}_{\mathrm{B}}=0\right) \end{aligned}$ | MJE15028, MJE15029 MJE15030, MJE15031 | ICEO | - | $\begin{aligned} & 0.1 \\ & 0.1 \end{aligned}$ | mAdc |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \left(\mathrm{V}_{C B}=120 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right) \\ & \left(\mathrm{V}_{\mathrm{CB}}=150 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0\right) \end{aligned}$ | MJE15028, MJE15029 <br> MJE15030, MJE15031 | $\mathrm{I}_{\text {CBO }}$ | - | $\begin{aligned} & 10 \\ & 10 \end{aligned}$ | $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current $\left(\mathrm{V}_{\mathrm{BE}}=5.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0\right)$ |  | $l_{\text {ebo }}$ | - | 10 | $\mu \mathrm{Adc}$ |

ON CHARACTERISTICS (Note 1)

| DC Current Gain $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=0.1 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=2.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=3.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=4.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right) \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 40 \\ & 40 \\ & 40 \\ & 20 \end{aligned}$ | $\begin{aligned} & \text { - } \\ & \text { - } \end{aligned}$ | - |
| :---: | :---: | :---: | :---: | :---: |
| DC Current Gain Linearity <br> ( $\mathrm{V}_{\text {CE }}$ From 2.0 V to 20 V , $\mathrm{IC}_{\mathrm{C}}$ From 0.1 A to 3 A ) <br> (NPN to PNP) | $\mathrm{h}_{\text {FE }}$ | $\begin{gathered} \text { Typ } \\ 2 \\ 3 \end{gathered}$ |  |  |
| Collector-Emitter Saturation Voltage $\left(I_{C}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.1 \mathrm{Adc}\right.$ ) | $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ | - | 0.5 | Vdc |
| Base-Emitter On Voltage $\left(I_{C}=1.0 \mathrm{Adc}, \mathrm{V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right)$ | $\mathrm{V}_{\mathrm{BE}}($ on) | - | 1.0 | Vdc |

DYNAMIC CHARACTERISTICS

| Current Gain - Bandwidth Product (Note 2) <br> $\left(\mathrm{I}_{\mathrm{C}}=500\right.$ mAdc, $\left.\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}_{\text {test }}=10 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 30 | - | MHz |
| :--- | :--- | :--- | :--- | :--- |

1. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$.
2. $\mathrm{f}_{\mathrm{T}}=\left|\mathrm{h}_{\mathrm{fe}}\right| \bullet \mathrm{f}_{\text {test }}$.


Figure 1. Power Derating

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Figure 2. Thermal Response


Figure 3. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{C}-V_{C E}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figures 3 and 4 is based on $\mathrm{T}_{\mathrm{J}(\mathrm{pk})}=150^{\circ} \mathrm{C}$; $\mathrm{T}_{\mathrm{C}}$ is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to $10 \%$ provided $\mathrm{T}_{\mathrm{J}(\mathrm{pk})}$ $<150^{\circ} \mathrm{C} . \mathrm{T}_{\mathrm{J}(\mathrm{pk})}$ may be calculated from the data in Figure 2. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.


Figure 4. Reverse-Bias Switching Safe Operating Area


Figure 5. Capacitances

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Figure 6. Small-Signal Current Gain



Figure 7. Current Gain-Bandwidth Product

PNP — MJE15029 MJE15031


Figure 8. DC Current Gain


Figure 9. "On" Voltage

## MJE15028, MJE15030 (NPN) MJE15029, MJE15031 (PNP)



Figure 10. Turn-On Times


Figure 11. Turn-Off Times

ORDERING INFORMATION

| Device | Package | Shipping |
| :--- | :---: | :---: |
| MJE15028 | TO-220 | 50 Units / Rail |
| MJE15028G | TO-220 <br> (Pb-Free) | 50 Units / Rail |
| MJE15029 | TO-220 | 50 Units / Rail |
| MJE15029G | TO-220 <br> (Pb-Free) | 50 Units / Rail |
| MJE15030 | TO-220 | 50 Units / Rail |
| MJE15030G | TO-220 <br> (Pb-Free) | 50 Units / Rail |
| MJE15031 | TO-220 | 50 Units / Rail |
| MJE15031G | TO-220 <br> (Pb-Free) | 50 Units / Rail |

## PACKAGE DIMENSIONS

TO-220AB
CASE 221A-09
ISSUE AA


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION:INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

|  | INCHES |  | MILLIMETERS |  |
| :---: | ---: | ---: | ---: | ---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.570 | 0.620 | 14.48 | 15.75 |
| B | 0.380 | 0.405 | 9.66 | 10.28 |
| C | 0.160 | 0.190 | 4.07 | 4.82 |
| D | 0.025 | 0.035 | 0.64 | 0.88 |
| F | 0.142 | 0.147 | 3.61 | 3.73 |
| G | 0.095 | 0.105 | 2.42 | 2.66 |
| H | 0.110 | 0.155 | 2.80 | 3.93 |
| J | 0.018 | 0.025 | 0.46 | 0.64 |
| K | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.15 | 1.52 |
| N | 0.190 | 0.210 | 4.83 | 5.33 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.15 | 1.39 |
| T | 0.235 | 0.255 | 5.97 | 6.47 |
| U | 0.000 | 0.050 | 0.00 | 1.27 |
| V | 0.045 | --- | 1.15 | --- |
| $\mathbf{Z}$ | --- | 0.080 | --- | 2.04 |

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

[^0]
## PUBLICATION ORDERING INFORMATION

## LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA

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